Diode Semiconductor Device - Page 1 of 1



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Inclosure M	laterial:
Metal	
Overall Len	igth:
0.375 inches	3
Terminal Le	ength:
1.625 inches	3
Overall Dia	meter:
Between 0.1	190 inches and 0.200 inches
Mounting N	lethod:
Terminal	
Terminal Ci	ircle Diameter:
0.200 inches	3
Semicondu	ctor Material:
Silicon	
Maximum C	Operating Tempurature Per Measurement Point:
80.0 degree	s celsius junction
Terminal Ty	ype And Quantity:
2 uninsulate	d wire lead
Shelf Life:	
N/a	
Unit Of Mea	isure:
Demilitariza	ation:
No	
Fiig:	
A110a0	